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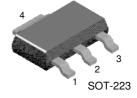


April 2006

FZT3019 NPN General Purpose Amplifier

Features

- This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 500 mA and collector voltages up to 80 V.
- · Sourced from process 12.



1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings * $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	80	V
V _{CBO}	Collector-Base Voltage	140	V
V _{EBO}	Emitter-Base Voltage	7.0	V
I _C	Collector current - Continuous	1.0	Α
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_C = 30 \text{ mA}, I_B = 0$	80		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	140		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 100 μA, I _C = 0	7.0		Vn
I _{CBO}	Collector Cutoff Current	V _{CB} = 90 V, I _E = 0		10	nA
		$V_{CB} = 90 \text{ V}, I_{E} = 0, T_{a} = 150^{\circ}\text{C}$		10	μΑ
I _{EBO}	Emitter-Cutoff Current	$V_{EB} = 5 V$,		10	nA
On Charac	teristics				
h _{FE}	DC Current Gain	$\begin{split} I_{C} &= 0.1 \text{ mA, V}_{CE} = 10 \text{ V} \\ I_{C} &= 10 \text{ mA, V}_{CE} = 10 \text{ V} \\ I_{C} &= 150 \text{ mA, V}_{CE} = 10 \text{ V} \\ I_{C} &= 500 \text{ mA, V}_{CE} = 10 \text{ V} \\ I_{C} &= 1.0 \text{ A, V}_{CE} = 10 \text{ V} \end{split}$	50 90 100 50 15	300	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 150 mA, I _B = 15 mA I _C = 500 mA, I _B = 50 mA		0.2 0.5	V V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 150 mA, I _B = 15 mA		1.1	V
	al Characteristics				•
f _T	Current Gain - Bandwidth Product	I _C = 50 mA, V _{CE} = 10 V, f = 20 MHz	100		MHz
C _{cob}	Collector-Base Capacitance	V _{CB} = 10 V, I _E = 0, f = 1.0 MHz		12	pF
C _{ibo}	Input Capacitance	$V_{BE} = 0.5 \text{ V}, I_{E} = 0, f = 1.0 \text{ MHz}$		60	pF
h _{fe}	Small Signal current Gain	I _C = 50 mA, V _{CE} = 10 V, f = 20 MHz	80	400	
rb'Cc	Collector Base Time Constant	I _C = 10 mA, V _{CB} = 10 V, f = 4.0 MHz		400	pS
NF	Noise Figure	$I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V},$ $R_S = 1.0 \text{k}\Omega, f = 1.0 \text{KHz}$		4.0	dB

^{*} Pulse Test: Pulse Width $\leq 300~\mu s,~Duty~Cycle \leq 2.0\%$

^{1.} These ratings are based on a maximum junction temperature of 150 degrees ${\rm C.}$

^{2.} These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_a=25^{\circ}C$ unless otherwise noted

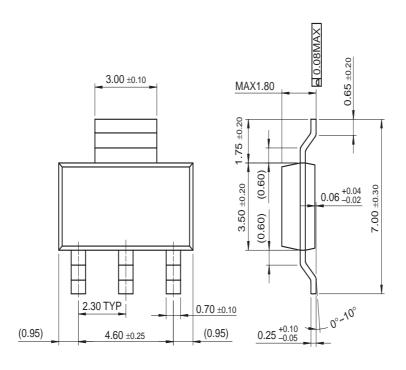
Symbol	Parameter	Max.	Units
P_{D}	Total Device Dissipation	1.0	W
	Derate above 25°C	8.0	mW/°C
R _{θJA} *	Thermal Resistance, Junction to Ambient	125	°C/W

NOTES :

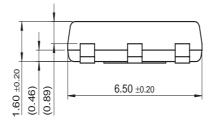
 $^{^\}star$ Device mounted on FR-4 PCB 36mm \times 18mm $\times 1.5$ mm, Mounting Pad for the collector lead is 600mm²

Package Dimensions

SOT-223



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Dimensions in Millimeters

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